

Rev.F Mar.-2016

TO-3P

Schottky Barrier Diode in a TO-3P Plastic Package.

Low forward voltage drop, low power losses, High efficiency operation.

OR-ing

DC-DC

For use in high frequency inverters, switching pow

Parameter	Symbol	Rating	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RM} V_{RWM} V_{DC}	150	V
RMS Reverse Voltage	V_{RMS}	105	V
Average forward current	$I_{F(AV)}$	2×15	A
Non-Repetitive Peak Forward Surge Current	I_{FSM}	250	A
Thermal Resistance Junction to Ambient case	$R_{\theta Jc}$	4.6	/W
Operating and Storage Temperature Range	T_j T_{stg}	-40 +150	

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Reverse Breakdown Voltage	V_{BR}	$I_R=1mA(T_a=25^\circ C)$	150			V
Forward Voltage	V_F	$I_F=5A(T_a=25^\circ C)$		0.69	0.75	V
		$I_F=10A(T_a=25^\circ C)$		0.76	0.85	V
		$I_F=15A(T_a=25^\circ C)$		0.81	0.90	V
		$I_F=5A(T_a=125^\circ C)$		0.55		V
		$I_F=10A(T_a=125^\circ C)$		0.62		V
		$I_F=15A(T_a=125^\circ C)$		0.67	0.75	V
Instantaneous Reverse current (Note 1)	I_R Note 1	$V_R=150V(T_a=25^\circ C)$		4	20	μA
		$V_R=150V(T_a=125^\circ C)$		5	10	mA

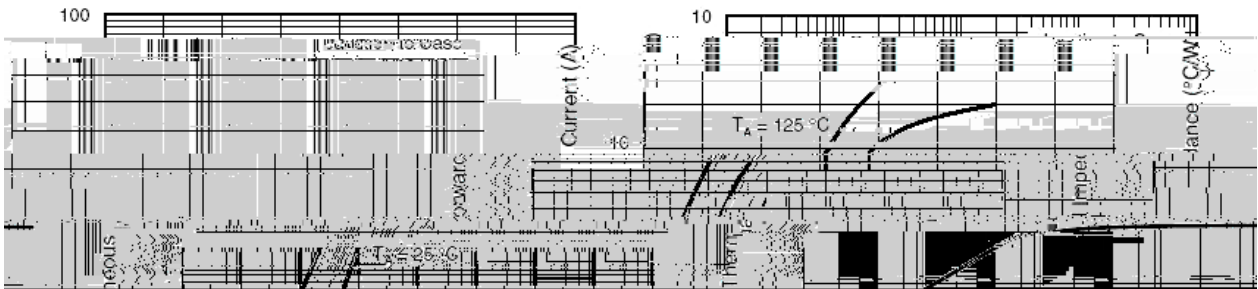
/Notes

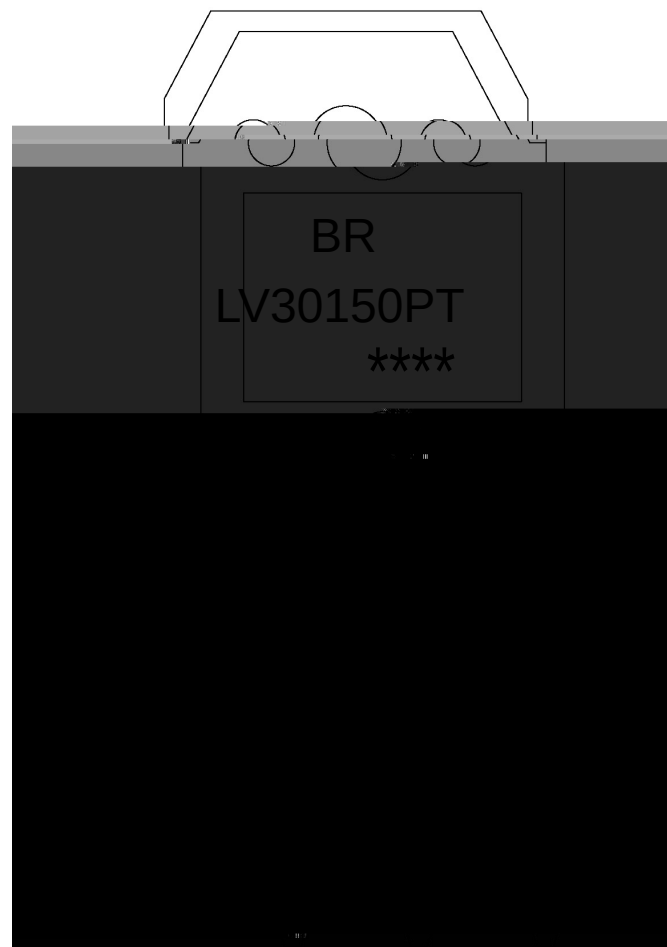
 1.
effect.

/Short duration pulse test used to minimize self-heating

 2.
single chip.

/ Unless otherwise noted, values for the parameters of a





BR

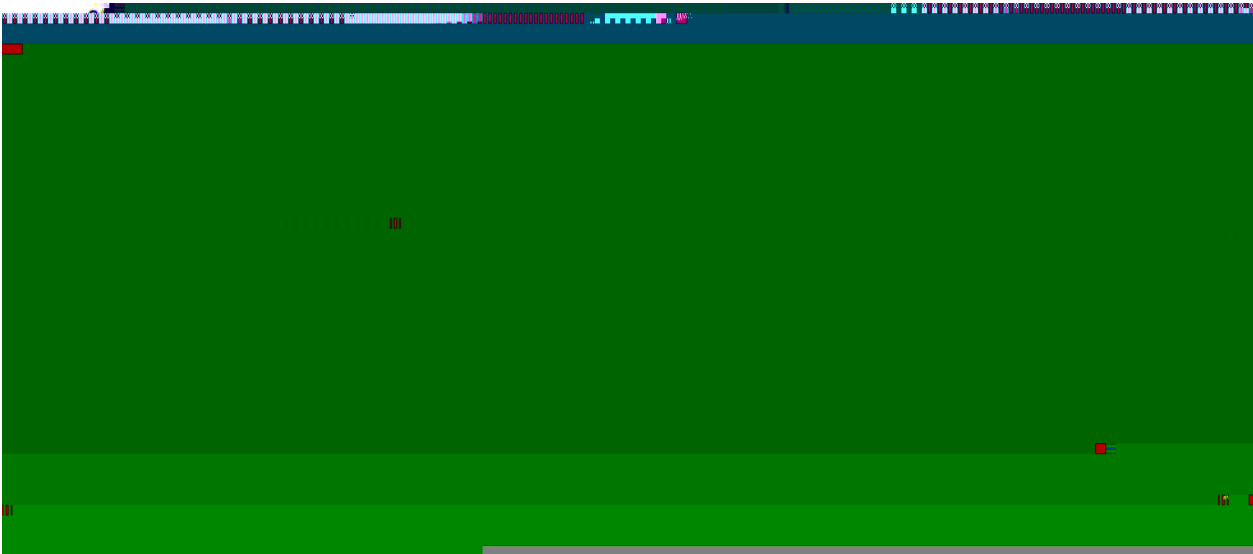
LV30150PT

Note:

BR: Company Code.

LV30150PT: Product Type.

****: Lot No. Code, code change with Lot No.



- 1

25 150

60 90sec;

2

255±5

5±0.5sec;

3

2 10

/sec.
- Note:

1.Preheating:25~150 , Time:60~90sec.

2.Peak Temp.:255±5 , Duration:5±0.5sec.

3. Cooling Speed: 2~10 /sec.

270±5

10±1 sec.

Temp.:270±5

Time:10±1 sec

/ TUBE

Package Type	Units					Dimension (unit mm ³)		
	Units/Tube /	Tubes/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Tube	Inner Box	Outer Box
TO-3P	30	15	450	5	2250	497.5×46×8	555×164×50	575 290 180